onsemi

Octal Buffer/Line Driver with 3-State Outputs

MC74AC540, MC74ACT540, MC74AC541, MC74ACT541

The MC74AC540/74ACT540 and MC74AC541/74ACT541 are octal buffer/line drivers designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers. The MC74AC541/74ACT541 is a noninverting option of the MC74AC540/74ACT540.

These devices are similar in function to the MC74AC240/74ACT240 and MC74AC244/74ACT244 while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes these devices especially useful as output ports for microprocessors, allowing ease of layout and greater PC board density.

Features

- 3-State Outputs
- Inputs and Outputs Opposite Side of Package, Allowing Easier Interface to Microprocessors
- Outputs Source/Sink 24 mA
- MC74AC540/74ACT540 Provides Inverted Outputs
- MC74AC541/74ACT541 Provides Noninverted Outputs
- 'ACT540 and 'ACT541 Have TTL Compatible Inputs
- These are Pb-Free Devices

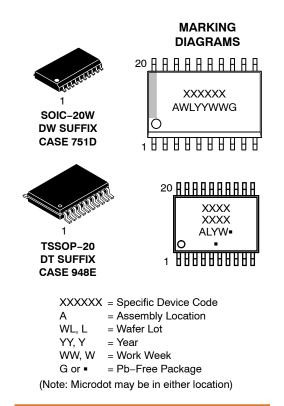
TRUTH TABLE

	Inputs		Out	outs
OE ₁	\overline{OE}_2	D	<i>'</i> 540	<i>'</i> 541
L H X L	L X H L	H X X L	L Z Z H	H Z Z L

H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial

Z = High Impedance



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

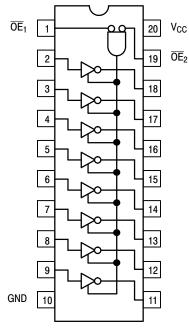


Figure 1. MC74AC540/74ACT540

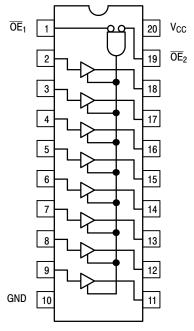


Figure 2. MC74AC541/74ACT541

MAXIMUM RATINGS

Symbol		Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to	GND)	-0.5 to +6.5	V
V _{IN}	DC Input Voltage (Referenced to GI	ND)	–0.5 to V _{CC} +0.5	V
V _{OUT}	DC Output Voltage (Referenced to 0	GND) (Note 1)	–0.5 to V _{CC} +0.5	V
Ι _{ΙΚ}	DC Input Diode Current		±20	mA
I _{OK}	DC Output Diode Current		±50	mA
I _{OUT}	DC Output Sink/Source Current		±50	mA
I _{CC}	DC Supply Current, per Output Pin		±50	mA
I _{GND}	DC Ground Current, per Output Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
ΤL	Lead temperature, 1 mm from Case	for 10 Seconds	260	°C
TJ	Junction Temperature Under Bias		140	°C
θ_{JA}	Thermal Resistance (Note 2)	SOIC TSSOP	96 150	°C/W
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 30% – 35%	UL 94 V-0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage	Human Body Model (Note 3) Charged Device Model (Note 4)	> 2000 > 1000	V
I _{Latchup}	Latchup Performance	Above V_{CC} and Below GND at 85°C (Note 5)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_{OUT} absolute maximum rating must be observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

3. Tested to EIA/JESD22-A114-A.

4. Tested to JESD22-C101-A.

5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Тур	Max	Unit
N	Quarke Matters	′AC	2.0	5.0	6.0	N
V _{CC}	Supply Voltage	′ACT	4.5	5.0	5.5	V
V _{IN} , V _{OUT}	DC Input Voltage, Output Voltage (Ref. to GND)	·	0	-	V _{CC}	V
		V _{CC} @ 3.0 V	-	150	-	
t _r , t _f	t _r , t _f // AC Devices except Schmitt Inputs	V _{CC} @ 4.5 V	-	40	-	ns/V
		V _{CC} @ 5.5 V	-	$\begin{array}{c cccc} 0 & 5.0 & 6.0 \\ 5 & 5.0 & 5.5 \\ 0 & - & V_{CC} \\ 150 & - \\ 40 & - \\ 25 & - \\ 10 & - \\ 8.0 & - \\ \end{array}$		
	Input Rise and Fall Time (Note 2)	V _{CC} @ 4.5 V	-	10	-	
t _r , t _f	ACT Devices except Schmitt Inputs	V _{CC} @ 5.5 V	-	8.0	-	ns/V
T _A	Operating Ambient Temperature Range	·	-40	25	85	°C
I _{ОН}	Output Current – High		-	-	-24	mA
I _{OL}	Output Current – Low		-	-	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1. V_{IN} from 30% to 70% V_{CC} ; see individual Data Sheets for devices that differ from the typical input rise and fall times. 2. V_{IN} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

			74	AC	74AC		
		V _{cc}	T _A = -	⊦25°C	T _A = −40°C to +85°C		
Symbol	Parameter	(V)	Тур	Gu	aranteed Limits	Unit	Conditions
V _{IH}	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$
V _{IL}	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$
V _{OH}	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	I _{OUT} = -50 μA
		3.0 4.5 5.5		2.56 3.86 4.86	2.46 3.76 4.76	V	$\label{eq:VIN} \begin{array}{c} {}^{*}V_{IN} = V_{IL} \text{ or } V_{IH} \\ -12 \text{ mA} \\ I_{OH} -24 \text{ mA} \\ -24 \text{ mA} \end{array}$
V _{OL}	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V	I _{OUT} = 50 μA
		3.0 4.5 5.5		0.36 0.36 0.36	0.44 0.44 0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ 12 mA I_{OL} 24 mA 24 mA
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μA	$V_{I} = V_{CC}, GND$
I _{OZ}	Maximum 3-State Current	5.5	-	±0.5	±5.0	μΑ	$V_{I} (OE) = V_{IL}, V_{IH}$ $V_{I} = V_{CC}, GND$ $V_{O} = V_{CC}, GND$
I _{OLD}	†Minimum Dynamic	5.5	-	-	75	mA	V _{OLD} = 1.65 V Max
I _{OHD}	Output Current	5.5	-	-	-75	mA	V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	-	8.0	80	μA	$V_{IN} = V_{CC}$ or GND

*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.

				74AC		74	AC		
		V _{cc} *	$T_A = +25^{\circ}C$ $T_A = -40^{\circ}C$ to $+85^{\circ}C$ $C_L = 50 \text{ pF}$ $C_L = 50 \text{ pF}$			Fig			
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Unit	No.
t _{PLH}	Propagation Delay Data to Output ('AC540)	3.3 5.0	1.5 1.5	5.5 4.0	7.5 6.0	1.0 1.0	8.0 6.5	ns	3–5
t _{PHL}	Propagation Delay Data to Output ('AC540)	3.3 5.0	1.5 1.5	5.0 4.0	7.0 5.5	1.0 1.0	7.5 6.0	ns	3–8
t _{PZH}	Output Enable Time ('AC540)	3.3 5.0	3.0 2.0	8.5 6.5	11 8.5	2.5 2.0	12 9.5	ns	3–3
t _{PZL}	Output Enable Time ('AC540)	3.3 5.0	2.5 2.0	7.5 6.0	10 7.5	2.0 1.5	11 8.5	ns	3-4
t _{PHZ}	Output Disable Time ('AC540)	3.3 5.0	2.5 1.5	8.5 7.5	13 10.5	1.5 1.0	14 11	ns	3–
t _{PLZ}	Output Disable Time ('AC540)	3.3 5.0	2.0 1.5	7.0 6.0	10 8.0	2.0 1.5	11 9.0	ns	3–8
t _{PLH}	Propagation Delay Data to Output ('AC541)	3.3 5.0	2.0 1.5	5.5 4.0	8.0 6.0	1.5 1.0	9.0 6.5	ns	3-
t _{PHL}	Propagation Delay Data to Output ('AC541)	3.3 5.0	2.0 1.5	5.5 4.0	8.0 6.0	1.5 1.0	8.5 6.5	ns	3–
t _{PZH}	Output Enable Time ('AC541)	3.3 5.0	3.0 2.0	8.0 6.0	11.5 8.5	3.0 1.5	12.5 9.5	ns	3-
t _{PZL}	Output Enable Time ('AC541)	3.3 5.0	2.5 1.5	7.0 5.5	10 7.5	2.5 1.0	11.5 8.5	ns	3-
t _{PHZ}	Output Disable Time ('AC541)	3.3 5.0	3.5 2.0	9.0 7.0	12.5 9.5	2.5 1.0	14 10.5	ns	3–
t _{PLZ}	Output Disable Time ('AC541)	3.3 5.0	2.5 2.0	6.5 5.5	9.5 7.5	2.0 1.0	10.5 8.5	ns	3-

AC CHARACTERISTICS (For Figures and Waveforms - See AND8277/D at www.onsemi.com)

*Voltage Range 3.3 V is 3.3 V ±0.3 V. Voltage Range 5.0 V is 5.0 V ±0.5 V.

DC CHARACTERISTICS

			74 /	СТ	74ACT		
		V _{cc}	T _A = -	⊦25°C	T _A = −40°C to +85°C		
Symbol	Parameter	(V)	Тур	Gu	aranteed Limits	Unit	Conditions
V _{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$
V _{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$
V _{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I _{OUT} = -50 μA
		4.5 5.5	-	3.86 4.86	3.76 4.76	V	$*V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} -24 \text{ mA}$ -24 mA
V _{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I _{OUT} = 50 μA
		4.5 5.5	-	0.36 0.36	0.44 0.44	V	$*V_{IN} = V_{IL} \text{ or } V_{IH}$ 24 mA I_{OL} 24 mA
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μA	V _I = V _{CC} , GND
ΔI_{CCT}	Additional Max. I _{CC} /Input	5.5	0.6	-	1.5	mA	$V_{I} = V_{CC} - 2.1 V$
I _{OZ}	Maximum 3-State Current	5.5	_	±0.5	±5.0	μΑ	$V_{I} (OE) = V_{IL}, V_{IH}$ $V_{I} = V_{CC}, GND$ $V_{O} = V_{CC}, GND$
I _{OLD}	†Minimum Dynamic	5.5	-	-	75	mA	V _{OLD} = 1.65 V Max
I _{OHD}	Output Current	5.5	-	-	-75	mA	V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	_	8.0	80	μΑ	V _{IN} = V _{CC} or GND

*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

				74ACT		744	СТ		
Symbol	Parameter	V _{CC} * (V)	T _A = +25°C C _L = 50 pF		$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $C_{L} = 50 \text{ pF}$		Unit	Fig. No.	
			Min	Тур	Max	Min	Max		
t _{PLH}	Propagation Delay Data to Output ('ACT540)	5.0	1.0	_	7.0	1.0	7.5	ns	3–5
t _{PHL}	Propagation Delay Data to Output ('ACT540)	5.0	1.0	-	8.0	1.0	8.5	ns	3–5
t _{PZH}	Output Enable Time ('ACT540)	5.0	1.0	_	10.5	1.0	11.5	ns	3–7
t _{PZL}	Output Enable Time ('ACT540)	5.0	1.0	_	9.5	1.0	10.5	ns	3–8
t _{PHZ}	Output Disable Time ('ACT540)	5.0	1.0	-	12.0	1.0	12.5	ns	3–7
t _{PLZ}	Output Disable Time ('ACT540)	5.0	1.5	-	9.0	1.0	10	ns	3–8
t _{PLH}	Propagation Delay Data to Output ('ACT541)	5.0	1.5	-	7.5	1.0	8.0	ns	3–5
t _{PHL}	Propagation Delay Data to Output ('ACT541)	5.0	1.5	_	7.5	1.0	8.0	ns	3–5
t _{PZH}	Output Enable Time ('ACT541)	5.0	2.0	_	10.0	1.0	11.0	ns	3–7
t _{PZL}	Output Enable Time ('ACT541)	5.0	1.5	_	9.5	1.0	10.5	ns	3–8
t _{PHZ}	Output Disable Time ('ACT541)	5.0	2.0	_	11.0	1.0	12.0	ns	3–7
t _{PLZ}	Output Disable Time ('ACT541)	5.0	2.0	-	9.0	1.0	10	ns	3–8

AC CHARACTERISTICS (For Figures and Waveforms – See AND8277/D at www.onsemi.com)

*Voltage Range 5.0 V is 5.0 V \pm 0.5 V.

CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0 V
C _{PD}	Power Dissipation Capacitance	30	pF	V _{CC} = 5.0 V

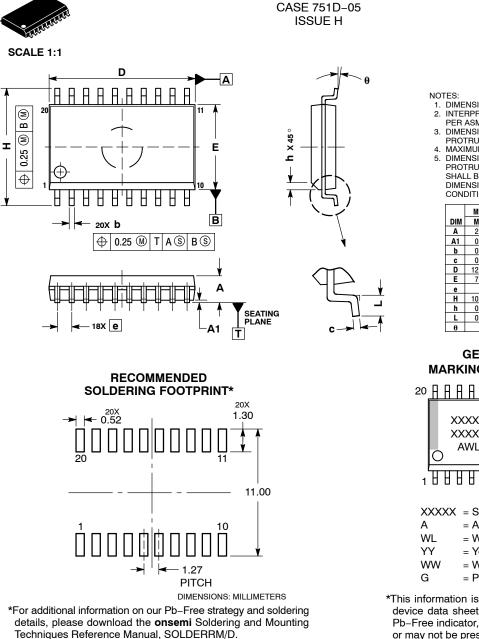
ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MC74AC540DWG	AC540	SOIC-20	38 Units / Rail
MC74AC540DWR2G	AC540	SOIC-20	1000 / Tape & Reel
MC74ACT540DWG	ACT540	SOIC-20	38 Units / Rail
MC74ACT540DWR2G	ACT540	SOIC-20	1000 / Tape & Reel
MC74ACT540DTR2G	ACT 540	TSSOP-20	2500 / Tape & Reel
MC74AC541DWG	AC541	SOIC-20	38 Units / Rail
MC74AC541DWR2G	AC541	SOIC-20	1000 / Tape & Reel
MC74ACT541DWG	ACT541	SOIC-20	38 Units / Rail
MC74ACT541DWR2G	ACT541	SOIC-20	1000 / Tape & Reel
MC74ACT541DWR2G-Q*	ACT541	SOIC-20	1000 / Tape & Reel
MC74AC541DTR2G	AC 541	TSSOP-20	2500 / Tape & Reel
MC74ACT541DTG	ACT 541	TSSOP-20	75 Units / Rail
MC74ACT541DTR2G	ACT 541	TSSOP-20	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging

Specifications Brochure, BRD8011/D. *-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

semi



SOIC-20 WB

DATE 22 APR 2015

- NOTES:
 DIMENSIONS ARE IN MILLIMETERS.
 INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD
- DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS				
DIM	MIN	MAX			
Α	2.35	2.65			
A1	0.10	0.25			
b	0.35	0.49			
C	0.23	0.32			
D	12.65	12.95			
E	7.40	7.60			
е	1.27	BSC			
н	10.05	10.55			
h	0.25	0.75			
L	0.50	0.90			
θ	0 °	7 °			

GENERIC **MARKING DIAGRAM***

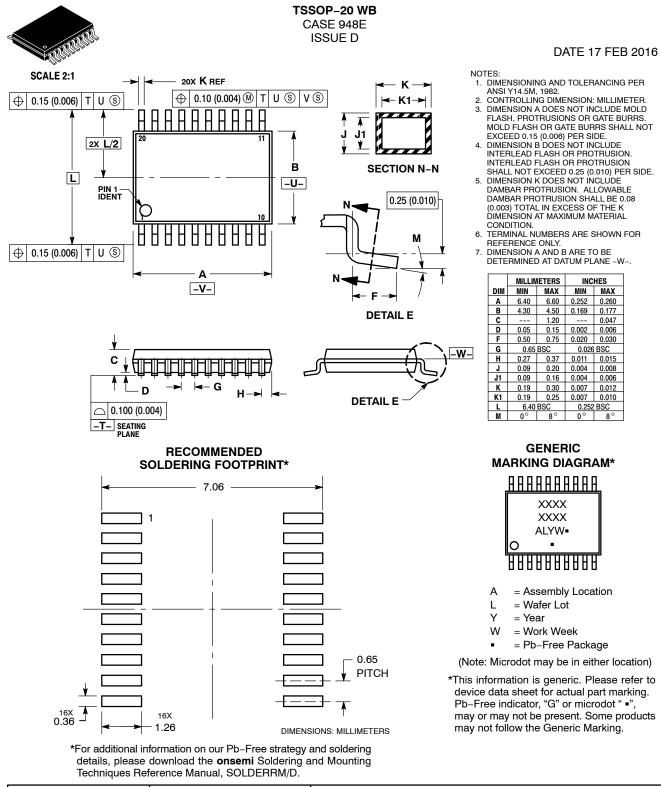
ХХХХХХХХХ ХХХХХХХХХ AWLYYWWG О
XXXXX = Specific Device Code A = Assembly Location WL = Wafer Lot YY = Year WW = Work Week

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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